

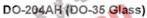
SD103A thru SD103C

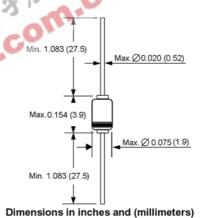
Small-Signal Diode Schottky Diodes

Features

- ◆ For general purpose applications
 ◆ The SD103 series is a Metal-on-silicon Schottky barrier device which is protected by a PN junction guard ring.
- ◆ The low forward voltage drop and fast switching make it ideal for protection of MOS devices, steering, biasing and coupling diodes for fast switching and low logic level applications.
- ◆ Other applications are click suppression, efficient full wave bridges in telephone subsets, and blocking diodes in rechargeable low voltage battery systems.
- ◆ These diodes are also available in the MiniMELF case with type designations LL103A thru LL103C.







Mechanical Data

◆ Case: DO-35 Glass Case

♦ Weight: approx. 0.13g

Maximum Ratings and Thermal Characteristics

(Ratings at 25°C ambient temperature unless otherwise specified.)

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Parameter	Symbol	Value	Unit							
Peak inverse voltage	SD103A SD103B SD103C	V _{RRM}	40 30 20	Volts						
Power dissipation (Infinite heatsink	P _{tot}	400 (1)	mW							
Single cycle surge 60 Hz sine wav	I _{FSM} 15		Amps							
Thermal resistance junction to amb	R _{eJA}	R _{eJA} 0.3 ⁽¹⁾								
Junction temperature		T _j 125 ⁽¹⁾		°C						
Storage temperature range	T _s	-55 to +150 ⁽¹⁾	∘C							

Notes: 1. Valid provided that leads at a distance of 4mm from case are kept at ambient temperature.

Electrical Characteristics

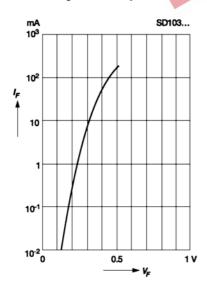
(T_J=25°C unless otherwise noted.)

Parameter		Symbol	Test Condition	Min.	Тур.	Max.	Unit
Leakage current	SD103A SD103B SD103C	I _R	$V_R=30V$ $V_R=20V$ $V_R=10V$	- - -	-	5 5 5	uА
Forward voltage drop		V _F	I _F =20mA I _F =200mA	-	-	0.37 0.6	Volt
Junction capacitance		C _{tot}	V _R =0V, f=1MHz	-	50	火门	pF
Reverse recovery time		t,,	I _F =I _R =50mA to 200mA, recover to 0.1I _R		10		ns

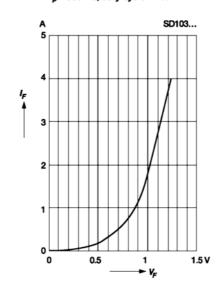
RATINGS AND CHARACTERISTIC CURVES

(T_A = 25°C unless otherwise noted)

Typical variation of fwd. current vs. fwd. voltage for primary conduction through the Schottky barrier



Typical high current forward conduction curve $t_p = 300$ ms, duty cycle = 2%



RATINGS AND CHARACTERISTIC CURVES

(T_A = 25°C unless otherwise noted)

